

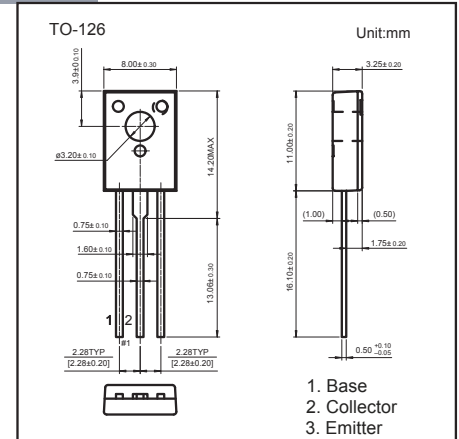
TO-126 Plastic-Encapsulate Transistors

FEATURES

- Power switching applications
- TRANSISTOR(NPN)

MECHANICAL DATA

- Case style:TO-126 molded plasti
- Mounting position:any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CB0}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_C	Collector Current -Continuous	1.5	A
P_C	Collector Power Dissipation	1.5	W
T_J	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55~150	°C

ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
3DD13003	TO-126	Bulk	200pcs/Bag
3DD13003-TU	TO-126	Tube	60pcs/Tube

Electrical Specification($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=5\text{mA}, I_E=0$	700			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=2\text{mA}, I_C=0$	9			V
Collector cut-off current	I_{CBO}	$V_{CB}=700\text{V}, I_E=0$			1	mA
Collector cut-off current	I_{CEO}	$V_{CE}=400\text{V}, I_B=0$			0.5	mA
Emitter cut-off current	I_{EBO}	$V_{EB}=9\text{V}, I_C=0$			1	mA
DC current gain	h_{FE1}	$V_{CE}=5\text{V}, I_C=0.5\text{A}$	8		40	
	h_{FE2}	$V_{CE}=5\text{V}, I_C=1.5\text{A}$	5			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=1\text{A}, I_B=0.25\text{A}$			0.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=1\text{A}, I_B=0.25\text{A}$			1.2	V
Transition frequency	f_T	$V_{CE}=10\text{V}, I_C=100\text{mA}, f=1\text{MHz}$	5			MHz
Fall time	t_f	$I_C=1\text{A}, I_{B1}=-I_{B2}=0.2\text{A}, V_{CC}=100\text{V}$			0.5	μs
Storage time	t_s	$I_C=250\text{mA}$ (UI9600)	2		4	μs

CLASSIFICATION OF $h_{FE(1)}$

Range	10-15	15-20	20-25	25-30	30-35	35-40

CLASSIFICATION OF t_s

Rank	A1	A2	B1	B2
Range	2-2.5 (μs)	2.5-3 (μs)	3-3.5 (μs)	3.5-4 (μs)

MARKING:13003

RATINGS AND CHARACTERISTIC CURVES

